## **SI-8008HD**

# DC-to-DC Step-Down Converter

#### **Selection Guide**

Part Number	Output Voltage Adjustable Range (V)	Efficiency, Typ. (%)	Input Voltage, Max. (V)	Output Current, Max. (A)	Packing
SI-8008HD-TL	0.8 to 24	83	40	5.5	800 pieces per reel

#### **Absolute Maximum Ratings**

Characteristic	Symbol	Remarks	Rating	Units
DC Input Voltage	V <sub>IN</sub>		43	V
Power Dissipation	P <sub>D</sub>	Mounted on 40 mm × 40 mm exposed copper area on 40 mm × 40 mm glass-epoxy PCB; limited by internal overtemperature protection.	3	W
Junction Temperature	TJ	Internal overtemperature protection circuit may enable when $T_J \ge 130^{\circ}C$ . During product operation, recommended $T_J \le 125^{\circ}C$ .	-40 to 150	°C
Storage Temperature	T <sub>stg</sub>		-40 to 150	°C
Thermal Resistance (junction-to-case)  R <sub>0JC</sub> Mounted on 40 mm × 40 mm exposed 40 mm glass-epoxy PCB.		Mounted on 40 mm × 40 mm exposed copper area on 40 mm × 40 mm glass-epoxy PCB.	3	°C/W
Thermal Resistance (junction-to-ambient air)	$R_{ heta JA}$	Mounted on 40 mm × 40 mm exposed copper area on 40 mm × 40 mm glass-epoxy PCB.	33.3	°C/W

#### **Recommended Operating Conditions\***

Characteristic	Symbol	Remarks	Min.	Max.	Units
DC Input Voltage Range	V <sub>IN</sub>	$V_{\rm IN}$ (min) is the greater of 4.5 V or $V_{\rm O}$ +3 V.	See remarks	40	V
DC Output Voltage Range	Vo		0.8	24	V
DC Output Current Range	Io	$V_{\text{IN}} \ge V_{\text{O}} + 3 \text{ V}$ ; to be used within the allowable package power dissipation characteristics (refer to Power Dissipation chart).	0	3.5	А
Operating Junction Temperature Range	T <sub>JOP</sub>		-30	100	°C
Operating Temperature Range	T <sub>OP</sub>	To be used within the allowable package power dissipation characteristics (refer to Power Dissipation chart).	-30	85	°C

Allegro MicroSystems, Inc.

www.allegromicro.com

115 Northeast Cutoff, Box 15036 Worcester, Massachusetts 01615-0036 (508) 853-5000

All performance characteristics given are typical values for circuit or system baseline design only and are at the nominal operating voltage and an ambient temperature,  $T_A$ , of 25°C, unless otherwise stated.





<sup>\*</sup>Required for normal device functioning according to Electrical Characteristics table.

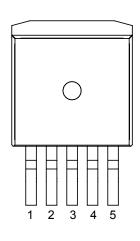
# DC-to-DC Step-Down Converter

### **ELECTRICAL CHARACTERISTICS**<sup>1</sup>, valid at $T_A$ = 25°C, $V_O$ = 5 V (adjusted), R1 = 4.2 k $\Omega$ , R1 = 0.8 k $\Omega$

Characteristic		Test Conditions	Min.	Тур.	Max.	Units
Reference Voltage	V <sub>ADJ</sub>	V <sub>IN</sub> = 15 V, I <sub>O</sub> = 0.2 A	0.784	0.800	0.816	V
Reference Voltage Temperature Coefficient	$\Delta V_{ADJ}/\Delta T$	$V_{IN}$ = 15 V, $I_{O}$ = 0.2 A, $T_{C}$ = 0 to 100 °C	-	±0.1	ı	mV/°C
Efficiency <sup>2</sup>	η	V <sub>IN</sub> = 15 V, I <sub>O</sub> = 3 A	_	83	-	%
Operating Frequency	f <sub>O</sub>	V <sub>IN</sub> = 15 V, I <sub>O</sub> = 3 A	_	150	_	kHz
Line Regulation	V <sub>Line</sub>	V <sub>IN</sub> = 10 to 30 V, I <sub>O</sub> = 3 A	_	60	80	mV
Load Regulation	$V_{Load}$	V <sub>IN</sub> = 15 V, I <sub>O</sub> = 0.2 to 5.5 A	_	20	50	mV
Overcurrent Protection Threshold Current	Is	V <sub>IN</sub> = 15 V	5.6	6.5	7.5	Α
SS Terminal On/Off Operation Threshold Voltage	V <sub>SSL</sub>		_	-	0.5	V
SS Terminal On/Off Operation Outflow Current	I <sub>SSL</sub>	V <sub>SSL</sub> = 0 V	_	10	30	μA
Quiescent Current 1	Iq	V <sub>IN</sub> = 15 V, I <sub>O</sub> = 0 A	-	6	_	mA
Quiescent Current 2	I <sub>q(off)</sub>	V <sub>IN</sub> = 15 V, V <sub>SS</sub> = 0 V	_	200	400	μΑ

<sup>&</sup>lt;sup>1</sup>Using circuit shown in Typical Application Circuit diagram.

#### **Pin-out Diagram**



#### **Terminal List Table**

Name	Number	Function		
IN	1	Supply voltage		
SW	2	Regulated supply output		
GND	3	Ground terminal		
ADJ	4	Terminal for resistor bridge feedback		
SS	5	The SS terminal is used to enable soft start and to control on/off operation of the IC output, $V_O$ (see figure 2). If neither soft start nor on/off control is used, leave pin open. To enable soft start, connect a capacitor between SS and ground. To control on/off operation, connect an NPN bipolar transistor, in a TTL open collector output configuration, between the SS terminal and GND. Turn off is done by decreasing $V_{SSL}$ below its rated level. When both soft start and $V_O$ on/off are used, a protection measure such as current limiting is required because, if the capacitance of C3 large, the discharge current of C3 flows across the transistor for on/off operation. Because a pull-up type resistor is provided inside the IC, no external voltage can be applied.		

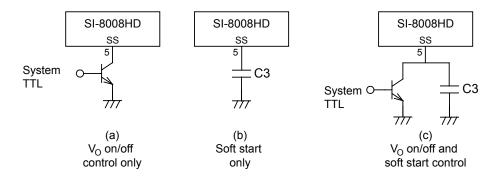


Figure 2. Alternative configurations for SS pin. If neither soft start nor V<sub>O</sub> on/off is required, the SS pin is left open.

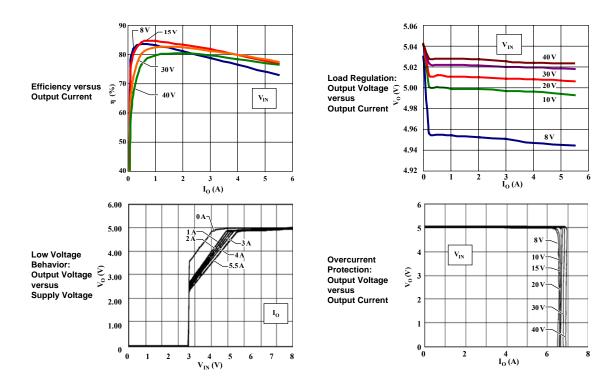


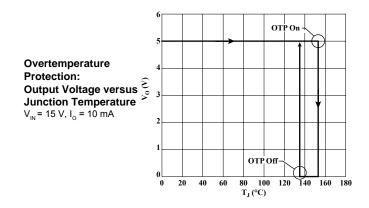


<sup>&</sup>lt;sup>2</sup>Efficiency is calculated as:  $\eta(\%) = ([V_O \times I_O] \times [V_{IN} \times I_{IN}]) \times 100$ .

### **Performance Characteristics**

at  $T_A$  = 25°C,  $V_O$  = 5 V adjusted, , R1 = 4.2 k $\Omega$ , R2 = 0.8 k $\Omega$ 







#### **Thermal Performance Characteristics**

The application must be designed to ensure that the  $T_J(max)$  of the device is not exceeded during operation. To do so, it is necessary to determine values for maximum power dissipation,  $P_D(max)$ , and ambient temperature,  $T_A(max)$ .

The relationships of  $T_J$ ,  $P_D$ ,  $T_A$ , and case temperature,  $T_C$ , are as shown in the following formulas:

$$P_{\rm D} = \frac{T_{\rm J} - T_{\rm C}}{R_{\rm \theta JC}}$$
 and  $P_{\rm D} = \frac{T_{\rm J} - T_{\rm A}}{R_{\rm \theta JA}}$ .

P<sub>D</sub> can be calculated from input values:

$$P_D = V_O \cdot I_O \left( \frac{100}{\eta_r} - 1 \right) - V_F \cdot I_O \left( 1 - \frac{V_O}{V_{IN}} \right)$$

where:

Vo is output voltage in V,

V<sub>IN</sub> is input supply voltage in V,

I<sub>O</sub> is output current in A,

 $\eta_x$  is IC efficiency in percent (varies with  $V_{IN}$  and  $I_O$ ; refer to efficiency performance curves for value), and

 $V_{\rm F}$  is forward voltage for the input diode, Di. In these tests, the Sanken FMB-G16L was used, at 0.55 V. For application design, obtain thermal data from the datasheet for the diode.

 $P_{\rm D}$  is substantially affected by the heat conductance properties of the application, in particular any exposed copper area on the PCB where the device is mounted. The relationships of  $P_{\rm D}$ ,  $T_{\rm A}$ , and copper area is represented in the Power Dissipation chart.

 $R_{\theta JA}$  for a given copper area can be determined form the Device Thermal Resistance chart. This can be substituted into the formula above to determine the  $T_J(max)$  allowable in the application. Generally, more than 10% to 20% derating is required.

Because the heat dissipation capacity of the copper area depends substantively on how it is used in the actual application, thermal characteristics of the application must be confirmed by testing.  $T_C$  is determined by connecting a thermocouple to the device as shown here:



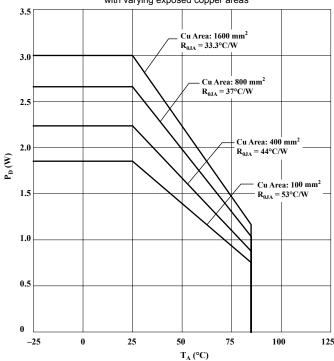
And analyzing the results using the following formula:

$$T_{\rm I} = P_{\rm D} \times R_{\rm \theta IC} + T_{C}$$
 ,

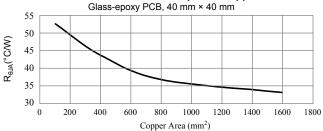
for this device,  $R_{\theta JC}$  is 3 °C/W.

### Power Dissipation versus Ambient Temperature T.(max) = 125°C: Mounted on glass-epoxy PCB (40 mm × 40 mm).

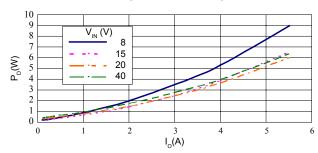
T<sub>J</sub>(max) = 125°C; Mounted on glass-epoxy PCB (40 mm × 40 mm), with varying exposed copper areas



#### Device Thermal Resistance versus Exposed Copper Area on PCB



#### **Power Dissipation versus Output Current**







#### **Component Selection**

**Diode Di** A Schottky-barrier diode must be used for Di. If other diode types are used, such as fast recovery diodes, the IC may be destroyed because of the reverse voltage applied by the recovery voltage or ON voltage.

**Choke Coil L1** If the winding resistance of the choke coil is too high, the efficiency may be reduced below rating. Because the overcurrent protection start current is approximately 6.5 A, attention must be paid to the heating of the choke coil by magnetic saturation due to overload or short-circuited load.

Capacitors C1, C2, C3, and C4 Because for SMPS, large ripple currents flow across C1 and C2, capacitors with high frequency and low impedance must be used. If the impedance of C2 is too high, the switching waveform may not be normal at low temperatures. Do not use either OS or tantalum types of capacitors for C2, because those cause an abnormal oscillation.

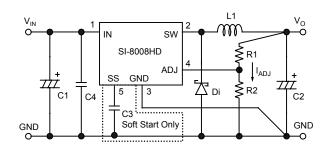
The device is stabilized, and for proper operation, C1 and C4 must be located close to the device (see layout diagram, below). C3 is required only if the soft start function is used. If not using soft-start, leave the SS terminal open. A pull-up resistor is provided inside the IC.

**Resistor Bridge** R1 and R2 comprise the resistor bridge for the output voltage, Vo, and are calculated as follows:

$$RI = \frac{(V_0 - V_{ADJ})}{I_{ADJ}} = \frac{(V_0 - 0.8)}{1 \times 10^{-3}} (\Omega) \text{ , and } R2 = \frac{V_{ADJ}}{I_{ADJ}} = \frac{0.8}{1 \times 10^{-3}} = 0.8 \text{ (k}\Omega)$$

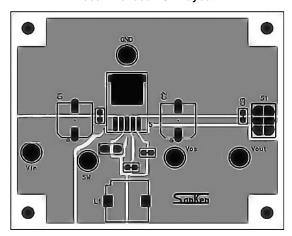
I<sub>ADJ</sub> should always be set to 1 mA. Note that R2 should always be present to ensure stable operation, even if V<sub>O</sub>, is set to 0.8 V (that is, even if there is no R1).  $V_O$  should be at least  $V_{IN} + 8\%$ .

#### **Typical Application Diagram**



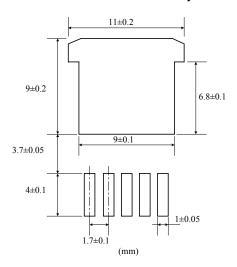
Component	Rating
C1	1500 μF
C2	1000 μF
C3	0.1 μF (For soft start function)
C4	4.7 μF (GRM32ER71H475KA88L)
Di	FMB-G16L (Sanken)
L1	100 μH

#### **Recommended PCB Layout**



All external components should be mounted as close as possible to the SI-8008HD. The ground of all components should be connected at one point near GND pin (pin 3).

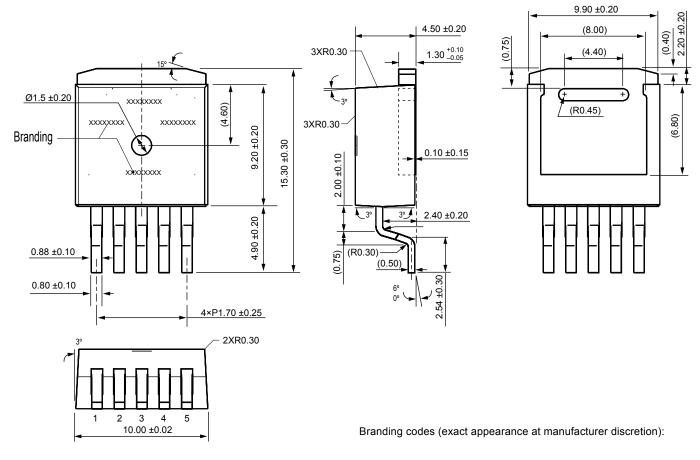
#### **Recommended Solder Pad Layout**





# DC-to-DC Step-Down Converter

#### PACKAGE OUTLINE DRAWING



Dimensions do not include mold protrusion Heastsink side flash: 0.8 mm maximum

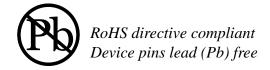
Dimensions in millimeters

1st line: SK 2nd line, lot: YMW X

Where: Y is the last digit of the year of manufacture

M is the month (1 to 9, O, N, D)
W is the week of the month (1 to 5)
X is the device subtype suffix number

3rd line, type: 8008HD

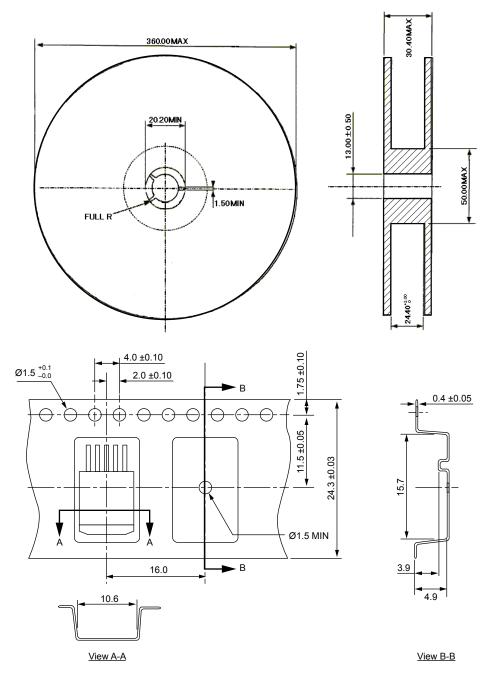






# DC-to-DC Step-Down Converter

#### TAPE AND REEL SPECIFICATION



Material: conductive polysterene

Camber < 1 mm over 100 length of tape

Pocket inner widths measured 0.3 mm above floor of pocket

Pocket position relative to sprocket hole measured to true position of pocket

10 sprocket hole pitch cumulative ±0.2 mm

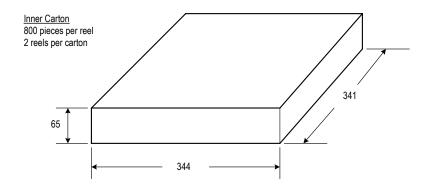
Pocket center and pocket hole center ±0.3 mm

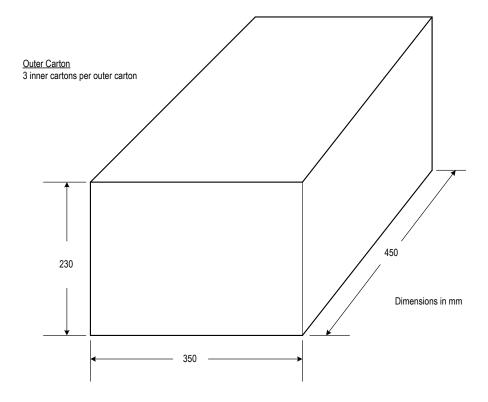
Surface resistivity  $< 10^7 \,\Omega$  / cm<sup>2</sup>





#### PACKING SPECIFICATION









### **SI-8008HD**

# DC-to-DC Step-Down Converter

**WARNING** — These devices are designed to be operated at lethal voltages and energy levels. Circuit designs that embody these components must conform with applicable safety requirements. Precautions must be taken to prevent accidental contact with power-line potentials. Do not connect grounded test equipment.

The use of an isolation transformer is recommended during circuit development and breadboarding.

#### **Cautions for Use**

- Operation of the product in parallel to increase current is not permitted.
- Although the product has an internal overtemperature protection circuit, that is intended only to protect the product from temporary excess heating due to overloads. Long-term reliability cannot be guaranteed when the product is operated under continuous overload conditions.

Because reliability can be affected adversely by improper storage environments and handling methods, please observe the following cautions.

#### **Cautions for Storage**

- Ensure that storage conditions comply with the standard temperature (5°C to 35°C) and the standard relative humidity (around 40 to 75%); avoid storage locations that experience extreme changes in temperature or humidity.
- Avoid locations where dust or harmful gases are present and avoid direct sunlight.
- Reinspect for rust on leads and solderability of products that have been stored for a long time.

#### **Cautions for Testing and Handling**

When tests are carried out during inspection testing and other standard test periods, protect the products from power surges from the testing device, shorts between adjacent products, and shorts to the heatsink.

#### **Electrostatic Discharge**

- When handling the products, operator must be grounded. Grounded wrist straps worn should have at least 1 MΩ of resistance to ground to prevent shock hazard.
- Workbenches where the products are handled should be grounded and be provided with conductive table and floor mats.
- When using measuring equipment such as a curve tracer, the equipment should be grounded.
- · When soldering the products, the head of soldering irons or the

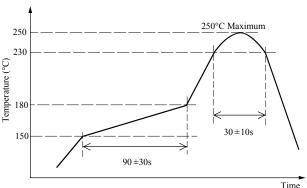
- solder bath must be grounded in other to prevent leak voltages generated by them from being applied to the products.
- The products should always be stored and transported in our shipping containers or conductive containers, or be wrapped in aluminum foil.

#### Soldering

When manually soldering the products, please be sure to minimize the working time, within the following limits:

Soldering Iron Temperature	Time
(°C)	(s)
380±10	3
300±10	(once only)

 Reflow soldering can be performed a maximum of twice, using the following recommended profile:





### **SI-8008HD**

# DC-to-DC Step-Down Converter

The products described herein are manufactured in Japan by Sanken Electric Co., Ltd. for sale by Allegro MicroSystems, Inc.

Sanken and Allegro reserve the right to make, from time to time, such departures from the detail specifications as may be required to permit improvements in the performance, reliability, or manufacturability of its products. Therefore, the user is cautioned to verify that the information in this publication is current before placing any order.

The information included herein is believed to be accurate and reliable. Application and operation examples described in this document are given for reference only and Sanken assumes no responsibility for any infringement of industrial property right, intellectual property rights or any other rights of Sanken or any third party which may result from its use.

When using the products herein, the applicability and suitability of such products for the intended purpose shall be the users responsibility to determine.

Although Sanken undertakes to enhance the quality and reliability of its products, the occurrence of failure and defect of semiconductor products at a certain rate is inevitable.

Users of Sanken products are requested to take, at their own risk, preventative measures including safety design of the equipment or systems against any possible injury, death, fires or damages to society due to device failure or malfunction.

Sanken products listed in this document are designed and intended for the use as components in general purpose electronic equipment or apparatus (home appliances, office equipment, telecommunication equipment, measuring equipment, etc.). When considering the use of Sanken products in the applications where higher reliability is required (transportation equipment and its control systems, traffic signal control systems or equipment, fire/crime alarm systems, various safety devices, etc.), please contact your nearest Sanken sales representative to discuss and obtain written confirmation of your specifications.

The use of Sanken products without the written consent of Sanken in the applications where extremely high reliability is required (aerospace equipment, nuclear power control systems, life support systems, etc.) is strictly prohibited. Anti-radioactive ray design is not considered for the products listed herein.

Copyright © 2007 Allegro MicroSystems, Inc. This datasheet is based on Sanken datasheet SSJ-03118

> For the latest version of this document, visit our website: www.allegromicro.com





oc to be step bown converter

# SI-8008HD

January, 2008

#### <Worldwide Contacts>

#### **Asia Pacific**

#### China

#### Sanken Electric Hong Kong Co., Ltd.

Suite 1026 Ocean Centre, Canton Road, Tsimshatsui, Kowloon, Hong Kong

Tel: 852-2735-5262 Fax: 852-2735-5494

#### Sanken Electric (Shanghai) Co., Ltd.

Room3202, Maxdo Centre, Xingyi Road 8, Changning district, Shanghai, China

Tel: 86-21-5208-1177 Fax: 86-21-5208-1757

#### Taiwan Sanken Electric Co., Ltd.

Room 1801, 18th Floor, 88 Jung Shiau East Road, Sec. 2, Taipei 100, Taiwan R.O.C.

Tel: 886-2-2356-8161 Fax: 886-2-2356-8261

#### <u>India</u>

#### Saket Devices Pvt. Ltd.

Office No.13, First Floor, Bandal - Dhankude Plaza, Near PMT Depot, Paud Road, Kothrud, Pune - 411 038, India

Tel: 91-20-5621-2340 91-20-2528-5449 Fax: 91-20-2528-5459

#### Japan

#### Sanken Electric Co., Ltd. Overseas Sales Headquaters

Metropolitan Plaza Bldg. 1-11-1 Nishi-Ikebukuro, Toshima-ku, Tokyo 171-0021, Japan

Tel: 81-3-3986-6164 Fax: 81-3-3986-8637

#### <u>Korea</u>

#### Sanken Electric Korea Co., Ltd.

Mirae Asset Life Bldg. 6F, 168 Kongduk-dong, Mapo-ku, Seoul, 121-705, Korea

Tel: 82-2-714-3700 Fax: 82-2-3272-2145

#### **Singapore**

#### Sanken Electric Singapore Pte. Ltd.

150 Beach Road, #14-03 The Gateway West, Singapore 189720

Tel: 65-6291-4755 Fax: 65-6297-1744 De to be step bown converter

# SI-8008HD

January, 2008

### **Europe**

#### **United Kingdom**

Sanken Power Systems (UK) Limited

Pencoed Technology Park Pencoed, Bridgend CF35 5HY. UK

Tel: 44-1656-869-100 Fax: 44-1656-869-162

### **North America**

#### **United States**

Allegro MicroSystems, Inc.

115 Northeast Cutoff, Worcester, Massachusetts 01606, U.S.A.

Tel: 1-508-853-5000 Fax: 1-508-853-3353

#### Allegro MicroSystems, Inc. (Southern California)

14 Hughes Street, Suite B105, Irvine, CA 92618

Tel: 1-949-460-2003 Fax: 1-949-460-7837